Main Unit Spec

Model Type	FPA-5510iV
Wafer Size	300mm, 200mm
Resolution	≤1.50µm
Numerical Aperture (NA)	0.10-0.18
Reticle Size	6in. (0.25in. thick)
Reduction Ratio	2:1
Field Size	52mm x 34mm
Overlay Accuracy	≤300nm (|m|+3σ) frontside ≤300nm (|m|+3σ) backside (option)

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